



**THE DATASHEET OF  
NTD80N02-001**



# NTD80N02

## Power MOSFET

### 24 V, 80 A, N-Channel DPAK

Designed for low voltage, high speed switching applications in power supplies, converters and power motor controls and bridge circuits.

#### Features

- These Devices are Pb-Free and are RoHS Compliant

#### Typical Applications

- Power Supplies
- Converters
- Power Motor Controls
- Bridge Circuits

#### MAXIMUM RATINGS (T<sub>J</sub> = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>	24	Vdc
Gate-to-Source Voltage - Continuous	V <sub>GS</sub>	±20	Vdc
Drain Current - Continuous @ T <sub>C</sub> = 25°C - Single Pulse (t <sub>p</sub> = 10 μs)	I <sub>D</sub> I <sub>DM</sub>	80* 200	Adc
Total Power Dissipation @ T <sub>C</sub> = 25°C	P <sub>D</sub>	75	Watts
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	°C
Single Pulse Drain-to-Source Avalanche Energy - Starting T <sub>J</sub> = 25°C (V <sub>DD</sub> = 24 Vdc, V <sub>GS</sub> = 10 Vdc, I <sub>L</sub> = 17 Apk, L = 5.0 mH, R <sub>G</sub> = 25 Ω)	E <sub>AS</sub>	733	mJ
Thermal Resistance - Junction-to-Case - Junction-to-Ambient (Note 1) - Junction-to-Ambient (Note 2)	R <sub>θJC</sub> R <sub>θJA</sub> R <sub>θJA</sub>	1.65 67 120	°C/W
Maximum Lead Temperature for Soldering Purposes, 1/8" from case for 10 seconds	T <sub>L</sub>	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. When surface mounted to an FR4 board using 1" pad size, (Cu Area 1.127 in<sup>2</sup>).
2. When surface mounted to an FR4 board using the minimum recommended pad size, (Cu Area 0.412 in<sup>2</sup>).

\*Chip current capability limited by package.

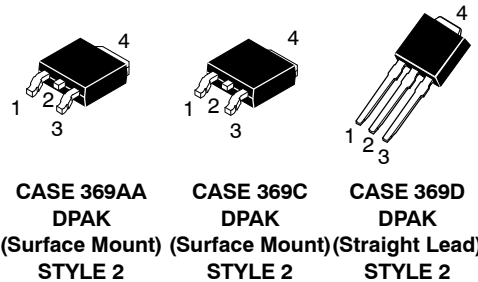
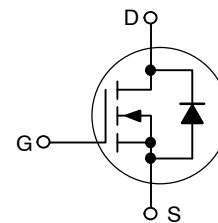


ON Semiconductor®

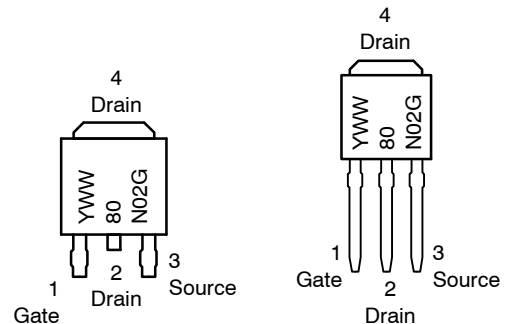
<http://onsemi.com>

V <sub>(BR)DSS</sub>	R <sub>DS(on)</sub> TYP	I <sub>D</sub> MAX
24 V	5.0 mΩ	80 A

#### N-Channel



#### MARKING DIAGRAMS & PIN ASSIGNMENTS



80N02 = Device Code  
 Y = Year  
 WW = Work Week  
 G = Pb-Free Package

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

# NTD80N02

## ELECTRICAL CHARACTERISTICS (T<sub>J</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
----------------	--------	-----	-----	-----	------

### OFF CHARACTERISTICS

Drain-to-Source Breakdown Voltage (Note 3) (V <sub>GS</sub> = 0 Vdc, I <sub>D</sub> = 250 μAdc) Positive Temperature Coefficient	V <sub>(BR)DSS</sub>	24 -	27 25	- -	Vdc mV/°C
Zero Gate Voltage Drain Current (V <sub>GS</sub> = 0 Vdc, V <sub>DS</sub> = 24 Vdc) (V <sub>GS</sub> = 0 Vdc, V <sub>DS</sub> = 24 Vdc, T <sub>J</sub> = 125°C)	I <sub>DSS</sub>	- -	- -	1.0 10	μAdc
Gate-Body Leakage Current (V <sub>GS</sub> = ±20 Vdc, V <sub>DS</sub> = 0 Vdc)	I <sub>GSS</sub>	-	-	±100	nAdc

### ON CHARACTERISTICS (Note 3)

Gate Threshold Voltage (Note 3) (V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μAdc) Negative Threshold Temperature Coefficient	V <sub>GS(th)</sub>	1.0 -	1.9 -3.8	3.0 -	Vdc mV/°C
Static Drain-to-Source On-Resistance (Note 3) (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 80 Adc) (V <sub>GS</sub> = 4.5 Vdc, I <sub>D</sub> = 40 Adc) (V <sub>GS</sub> = 10 Vdc, I <sub>D</sub> = 20 Adc) (V <sub>GS</sub> = 4.5 Vdc, I <sub>D</sub> = 20 Adc)	R <sub>DS(on)</sub>	- - - -	5.0 7.5 5.0 7.5	5.8 9.0 5.8 9.0	mΩ
Forward Transconductance (V <sub>DS</sub> = 15 Vdc, I <sub>D</sub> = 10 Adc) (Note 3)	g <sub>FS</sub>	-	20	-	Mhos

### DYNAMIC CHARACTERISTICS

Input Capacitance	(V <sub>DS</sub> = 20 Vdc, V <sub>GS</sub> = 0 V, f = 1.0 MHz)	C <sub>ISS</sub>	-	2250	2600	pF
Output Capacitance		C <sub>OSS</sub>	-	900	1100	
Transfer Capacitance		C <sub>rSS</sub>	-	400	525	

### SWITCHING CHARACTERISTICS (Note 4)

Turn-On Delay Time	(V <sub>GS</sub> = 4.5 Vdc, V <sub>DD</sub> = 20 Vdc, I <sub>D</sub> = 20 Adc, R <sub>G</sub> = 2.5 Ω)	t <sub>d(on)</sub>	-	17	30	ns
Rise Time		t <sub>r</sub>	-	67	125	
Turn-Off Delay Time		t <sub>d(off)</sub>	-	28	45	
Fall Time		t <sub>f</sub>	-	40	75	
Gate Charge	(V <sub>GS</sub> = 4.5 Vdc, I <sub>D</sub> = 20 Adc, V <sub>DS</sub> = 20 Vdc) (Note 3)	Q <sub>T</sub>	-	30	42	nC
		Q <sub>1</sub>	-	7.0	12	
		Q <sub>2</sub>	-	18	28	

### SOURCE-DRAIN DIODE CHARACTERISTICS

Forward On-Voltage (I <sub>S</sub> = 20 Adc, V <sub>GS</sub> = 0 Vdc) (Note 3) (I <sub>S</sub> = 40 Adc, V <sub>GS</sub> = 0 Vdc) (I <sub>S</sub> = 20 Adc, V <sub>GS</sub> = 0 Vdc, T <sub>J</sub> = 150°C)	V <sub>SD</sub>	- - -	0.92 1.05 0.70	1.2 - -	Vdc
Reverse Recovery Time  (I <sub>S</sub> = 20 Adc, V <sub>GS</sub> = 0 Vdc, dI <sub>S</sub> /dt = 100 A/μs) (Note 3)	t <sub>rr</sub>	-	38	52	ns
	t <sub>a</sub>	-	20	-	
	t <sub>b</sub>	-	18	-	
Reverse Recovery Stored Charge	Q <sub>rr</sub>	-	0.038	-	μC

- Pulse Test: Pulse Width ≤ 300 μs, Duty Cycle ≤ 2%.
- Switching characteristics are independent of operating junction temperatures.

# NTD80N02

## TYPICAL CHARACTERISTICS

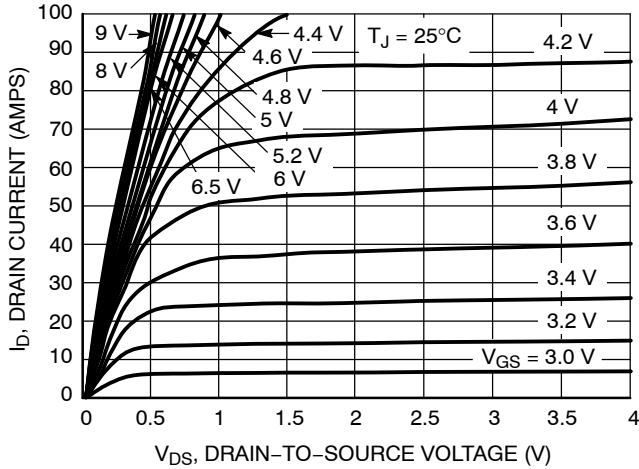


Figure 1. On-Region Characteristics

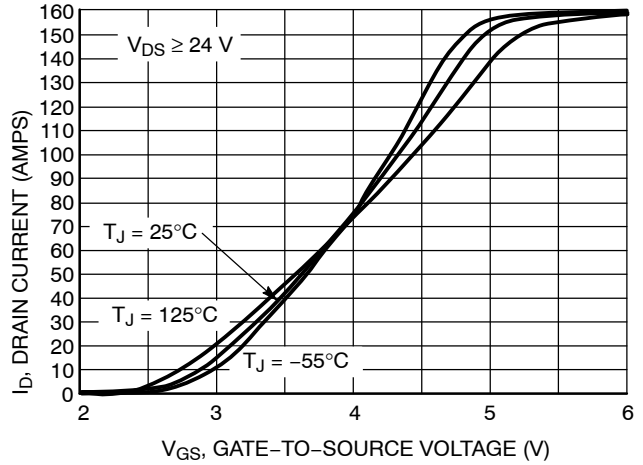


Figure 2. Transfer Characteristics

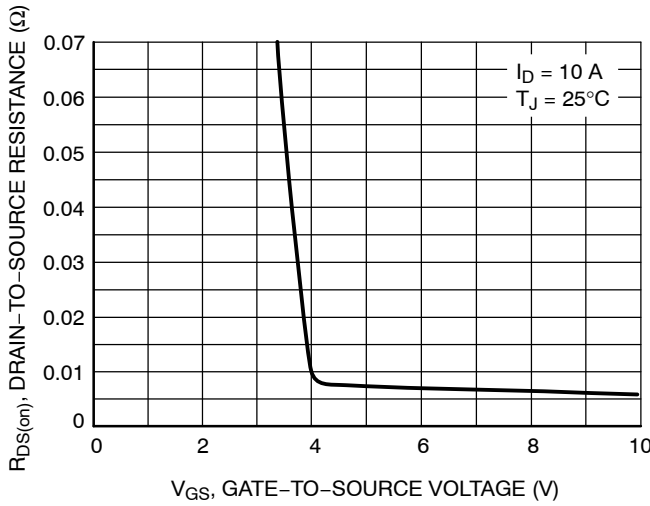


Figure 3. On-Resistance versus Gate-to-Source Voltage

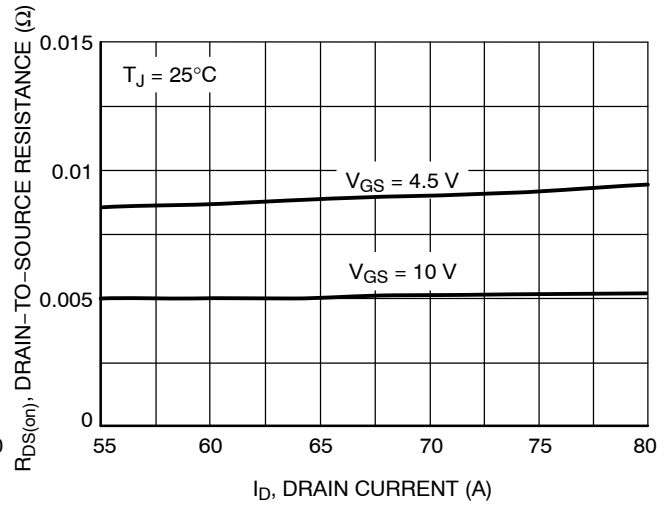


Figure 4. On-Resistance versus Drain Current and Gate Voltage

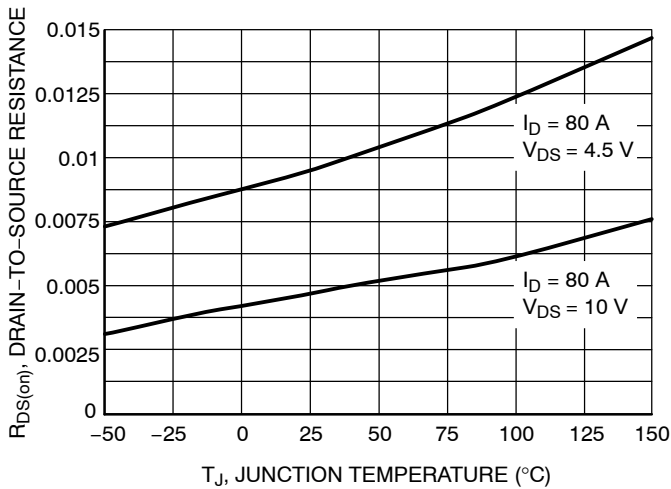


Figure 5. On-Resistance Variation with Temperature

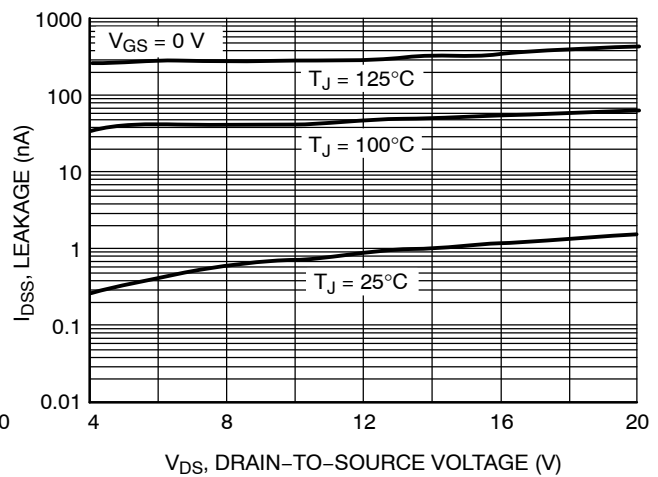


Figure 6. Drain-to-Source Leakage Current versus Voltage

TYPICAL CHARACTERISTICS

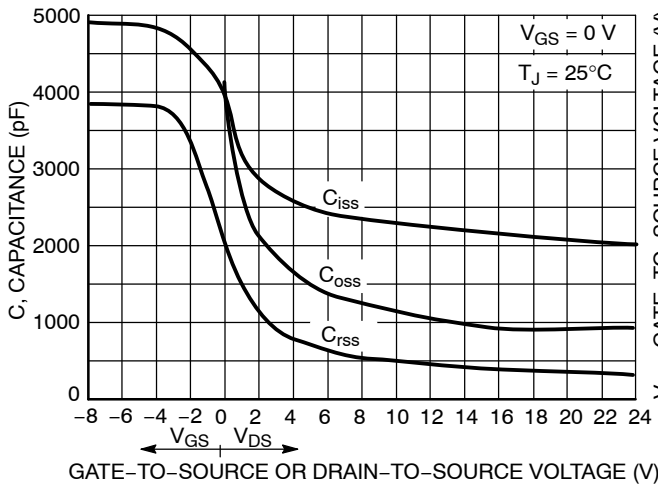


Figure 7. Capacitance Variation

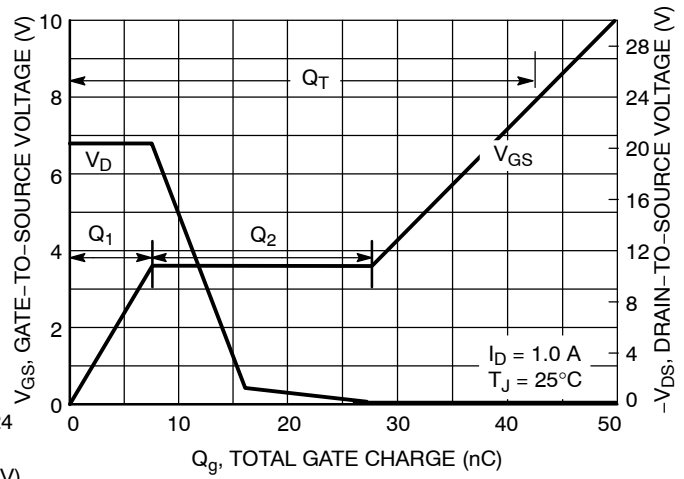


Figure 8. Gate-to-Source and Drain-to-Source Voltage versus Total Charge

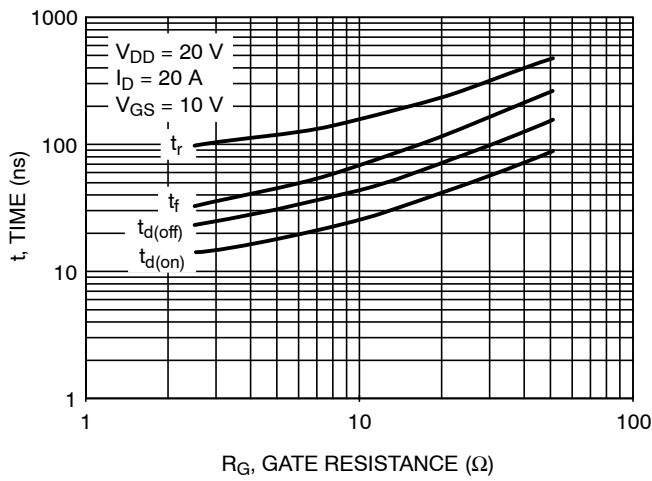


Figure 9. Resistive Switching Time Variation versus Gate Resistance

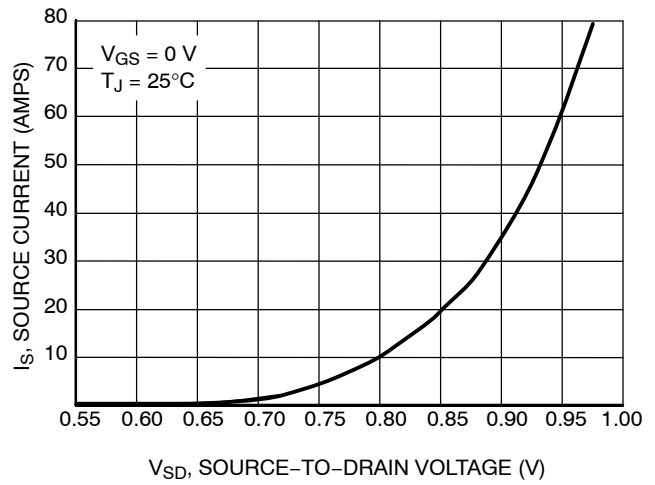
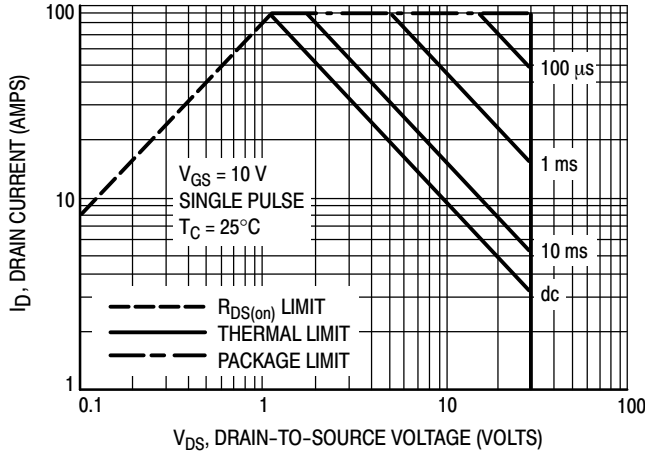


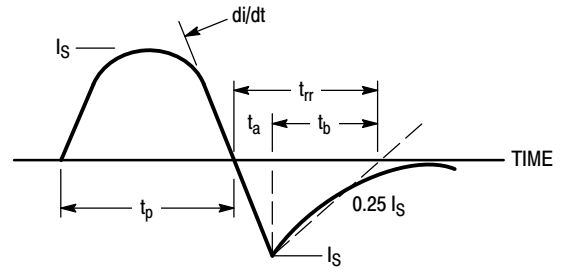
Figure 10. Diode Forward Voltage versus Current

# NTD80N02

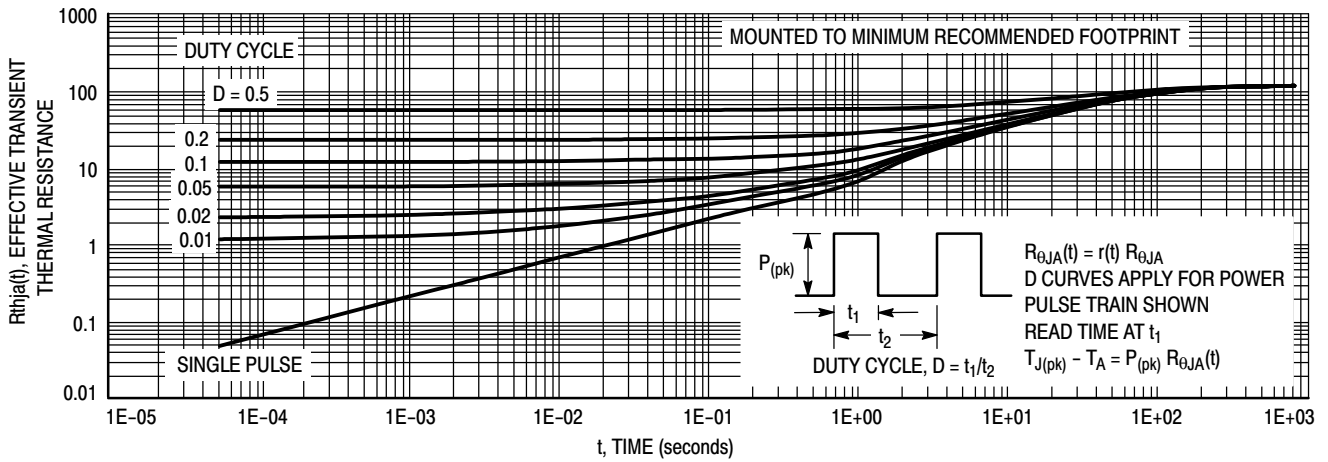
## TYPICAL CHARACTERISTICS



**Figure 11. Maximum Rated Forward Biased Safe Operating Area**



**Figure 12. Diode Reverse Recovery Waveform**



**Figure 13. Thermal Response - Various Duty Cycles**

### ORDERING INFORMATION

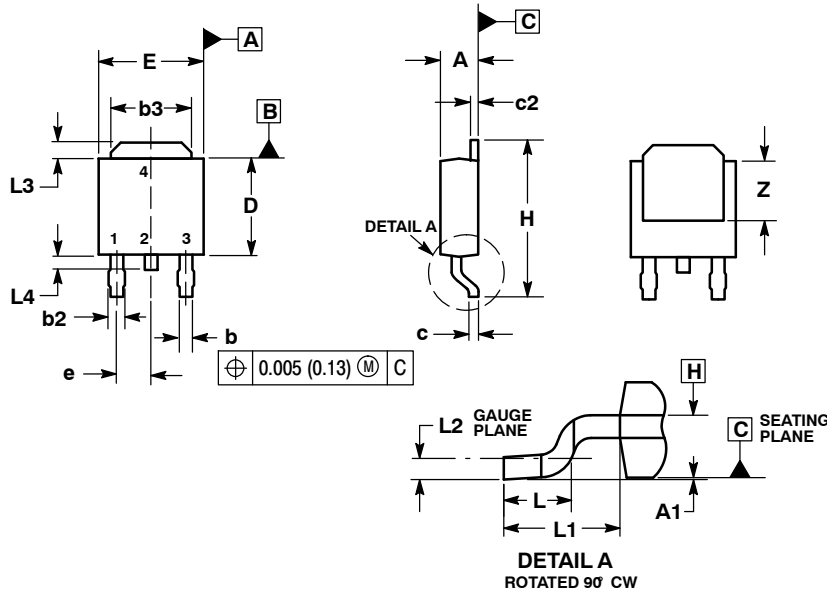
Order Number	Package	Shipping†
NTD80N02T4G	DPAK-3 (Pb-Free)	2500 / Tape & Reel
NTD80N02-1G	DPAK-3 Straight Lead (Pb-Free)	75 Units / Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NTD80N02

## PACKAGE DIMENSIONS

### DPAK (SINGLE GAUGE) CASE 369AA-01 ISSUE B

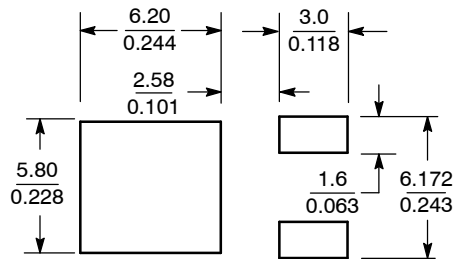


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.086	0.094	2.18	2.38
A1	0.000	0.005	0.00	0.13
b	0.025	0.035	0.63	0.89
b2	0.030	0.045	0.76	1.14
b3	0.180	0.215	4.57	5.46
c	0.018	0.024	0.46	0.61
c2	0.018	0.024	0.46	0.61
D	0.235	0.245	5.97	6.22
E	0.250	0.265	6.35	6.73
e	0.090 BSC		2.29 BSC	
H	0.370	0.410	9.40	10.41
L	0.055	0.070	1.40	1.78
L1	0.108 REF		2.74 REF	
L2	0.020 BSC		0.51 BSC	
L3	0.035	0.050	0.89	1.27
L4	---	0.040	---	1.01
Z	0.155	---	3.93	---

### SOLDERING FOOTPRINT\*



SCALE 3:1  $\left(\frac{\text{mm}}{\text{inches}}\right)$

**STYLE 2:**

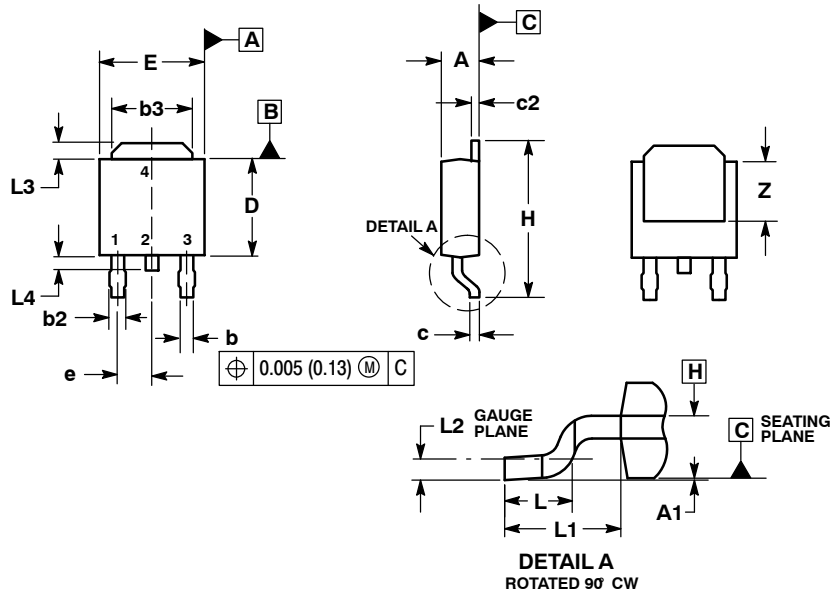
- PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# NTD80N02

## PACKAGE DIMENSIONS

### DPAK (SINGLE GAUGE) CASE 369C-01 ISSUE D



#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: INCHES.
3. THERMAL PAD CONTOUR OPTIONAL WITHIN DIMENSIONS b3, L3 and Z.
4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.006 INCHES PER SIDE.
5. DIMENSIONS D AND E ARE DETERMINED AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY.
6. DATUMS A AND B ARE DETERMINED AT DATUM PLANE H.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
<b>A</b>	0.086	0.094	2.18	2.38
<b>A1</b>	0.000	0.005	0.00	0.13
<b>b</b>	0.025	0.035	0.63	0.89
<b>b2</b>	0.030	0.045	0.76	1.14
<b>b3</b>	0.180	0.215	4.57	5.46
<b>c</b>	0.018	0.024	0.46	0.61
<b>c2</b>	0.018	0.024	0.46	0.61
<b>D</b>	0.235	0.245	5.97	6.22
<b>E</b>	0.250	0.265	6.35	6.73
<b>e</b>	0.090 BSC		2.29 BSC	
<b>H</b>	0.370	0.410	9.40	10.41
<b>L</b>	0.055	0.070	1.40	1.78
<b>L1</b>	0.108 REF		2.74 REF	
<b>L2</b>	0.020 BSC		0.51 BSC	
<b>L3</b>	0.035	0.050	0.89	1.27
<b>L4</b>	---	0.040	---	1.01
<b>Z</b>	0.155	---	3.93	---

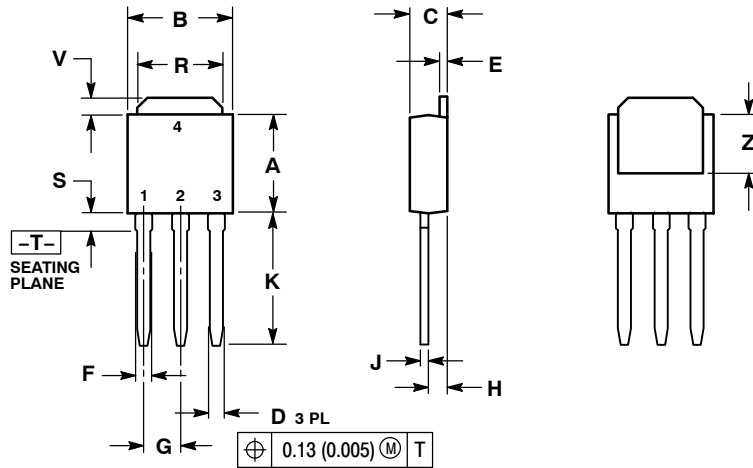
#### STYLE 2:

- PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

# NTD80N02

## PACKAGE DIMENSIONS

### DPAK CASE 369D-01 ISSUE B



**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.235	0.245	5.97	6.35
B	0.250	0.265	6.35	6.73
C	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.018	0.023	0.46	0.58
F	0.037	0.045	0.94	1.14
G	0.090 BSC		2.29 BSC	
H	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.350	0.380	8.89	9.65
R	0.180	0.215	4.45	5.45
S	0.025	0.040	0.63	1.01
V	0.035	0.050	0.89	1.27
Z	0.155	---	3.93	---

**STYLE 2:**

- PIN 1. GATE  
 2. DRAIN  
 3. SOURCE  
 4. DRAIN

ON Semiconductor and are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### PUBLICATION ORDERING INFORMATION

**LITERATURE FULFILLMENT:**

Literature Distribution Center for ON Semiconductor  
 P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3867 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** orderlit@onsemi.com

**N. American Technical Support:** 800-282-9855 Toll Free  
 USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
 Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
 Phone: 81-3-5773-3850



**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)

**Order Literature:** <http://www.onsemi.com/orderlit>

For additional information, please contact your local Sales Representative

## Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

-  [View NTD80N02-001 on WIN SOURCE](#)
-  [ON Semiconductor Information](#)

## Optimize Your Supply Chain with WIN SOURCE Solutions

-  Global Sourcing Solution
-  Obsolete Management
-  Cost Control Management
-  Shortage Management
-  Alternative Solution
-  Excess Inventory Management